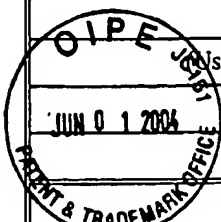


U.S. Department of Commerce, Patent and Trademark	Atty. Docket No.	Application No.
INFORMATION DISCLOSURE STATEMENT BY APPLICANT	SNDK.268US1	10/665,828
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(Use several sheets if necessary)	Raul-Adrian Cernea and Yan Li	6022
	Filing Date	Group
	September 17, 2003	2818



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*Examiner Initial		Document Number	Date	Name	Class	Subclass	Filing Date If Appropriate
DL	1	4,785,427	Nov. 15, 1988	Young			
	2	5,093,806	Mar. 3, 1992	Tran			
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*Examiner Initial		Document Number	Date	Name	Class	Subclass	Filing Date If Appropriate

## Foreign Patent Documents

							Translation	
		Document	Date	Country	Class	Subclass	Yes	No
DL	9	1134746 A2	Sep. 19, 2001	Europe				
DL	10	WO 02/069340	Sep. 6, 2002	WIPO				

## OTHER ART (Including Author, Title, Date, Pertinent Pages, Etc.)

DL	11	International Search Report corresponding to PCT/US03/30133, International Searching Authority, European Patent Office, filed September 18, 2003, 4 pages
DL	12	Eitan et al., "NROM: A Novel Localized Trapping 2-Bit Nonvolatile Memory Cell," IEEE Electron Device Letters, vol. 21, no. 11, Nov. 2000, pp. 543-545

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Date Considered

12/04

\*EXAMINER: Initial if reference considered, whether or not citation is in conformance with MPEP 609; Draw line through citation if not in conformance and not considered. Include copy of this form with your communication to applicant.